

主要特点

- ◆ 输出电流 0.5A
- ◆ 输出电压 5V
- ◆ 过热保护、短路保护
- ◆ 输出晶体管 SOA 保护

极限值

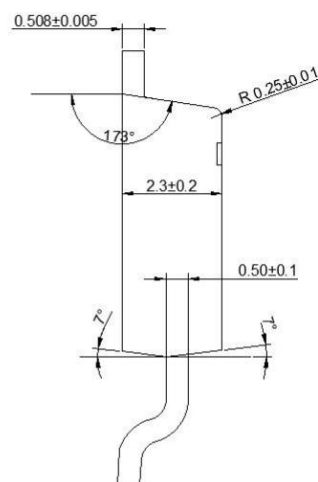
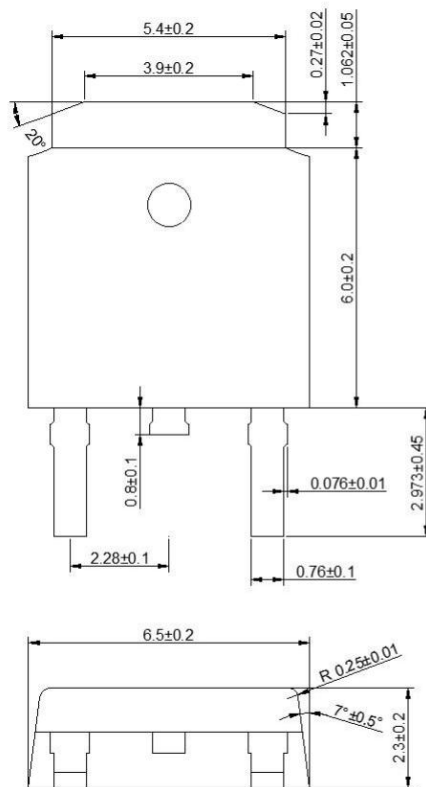
- VI--输入电压: 36V
- TOPR--工作结温范围: 0~150℃
- TSTG--储存温度范围: -55~150℃


TO-252


1-INPUT

2-GND

3-OUTPUT



单位:mm
TO-252

极限参数

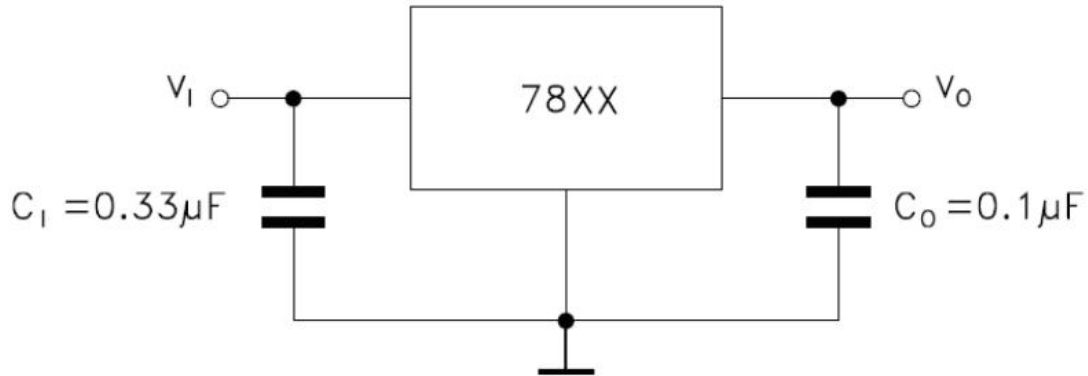
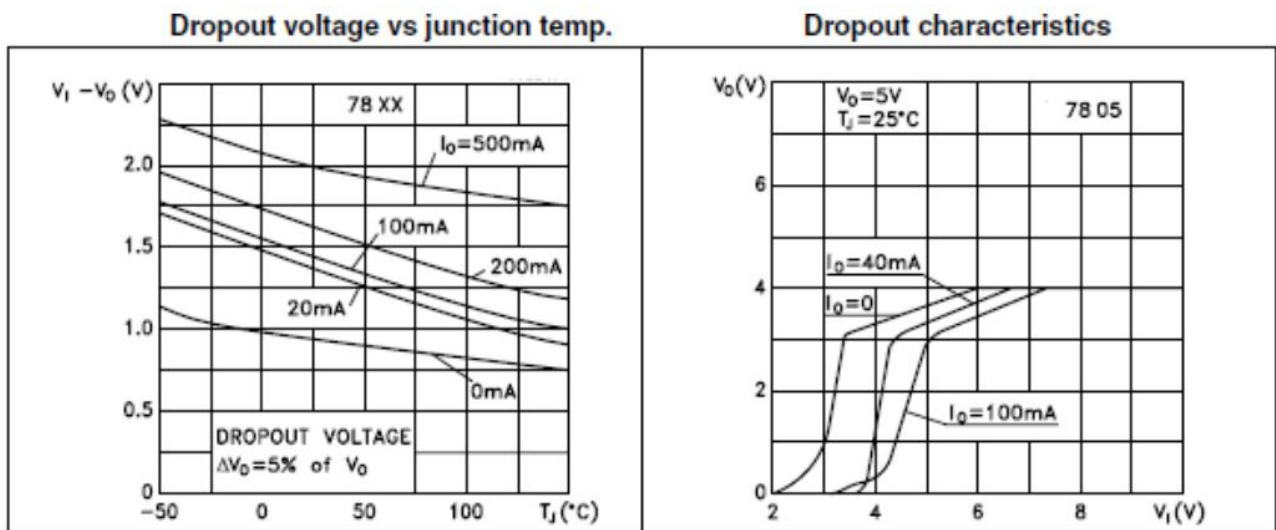
参数名称	符号	额定值	单位
输入电压	V_{IN}	36	V
最大输电流	I_{out}	500	mA
工作结温	T_j	0~+150	°C
贮存温度	T_{stg}	-55~+150	°C
功耗	P_d	1.5	W

电参数

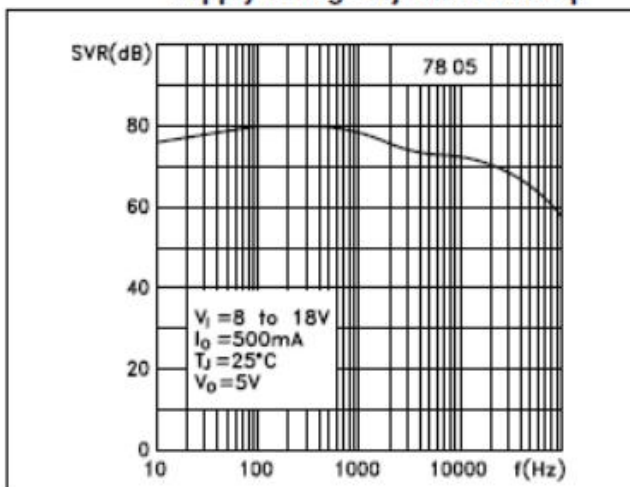
参数符号	符 号 说 明	最小值	典型值	最大值	单 位	测 试 条 件
V_o	输出电压	4.8	5.0	5.2	V	$T_j=25^{\circ}\text{C}$
		4.75	5.0	5.25		$I_o=250\text{mA}$ $V_I=10\text{V}$
ΔV_o	电压调整率*		5.0	50	mV	$I_o=250\text{mA}$, $7.0\text{V} \leq V_I \leq 11\text{V}$
ΔV_o	负载调整率*		-40	40	mV	$V_I=10\text{V}$, $5.0\text{mA} \leq I_o \leq 250\text{mA}$
			-80	80		$V_I=10\text{V}$, $5.0\text{mA} \leq I_o \leq 500\text{mA}$
I_q	静态电流		1	5	mA	$V_I=10\text{V}$ $I_o=5\text{mA}$
ΔI_q	静态电流变化率	-0.4		0.4	mA	$V_I=7\text{V}$, $5.0\text{mA} \leq I_o \leq 250\text{mA}$
		-0.7		0.7		$7.0\text{V} \leq V_I \leq 26\text{V}$, $I_o=50\text{mA}$
I_{cc}	电源电流			9	mA	$V_I=36\text{V}$ $I_o=0\text{mA}$

+5V Voltage regulator

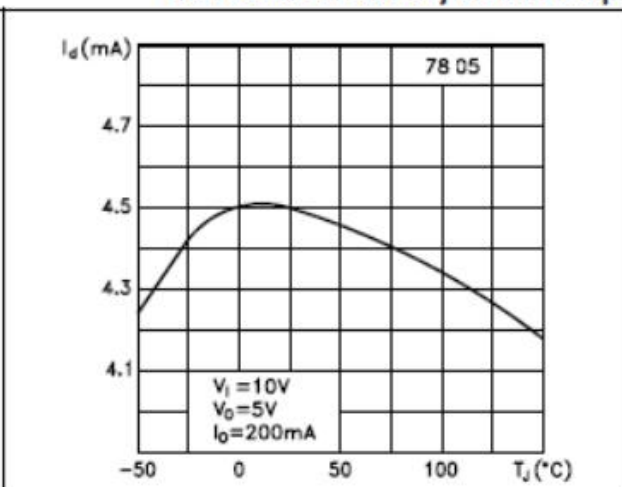
(参见测试电路, 除非另有说明, $0^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$, $I_O=500\text{mA}$, $V_I=10\text{V}$, $C_I=0.33\mu\text{F}$, $C_O=0.1\mu\text{F}$)

测试原理图

曲线图


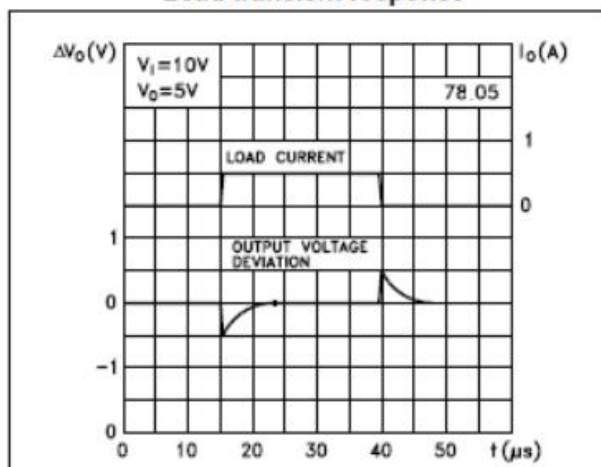
Supply voltage rejection vs freq.



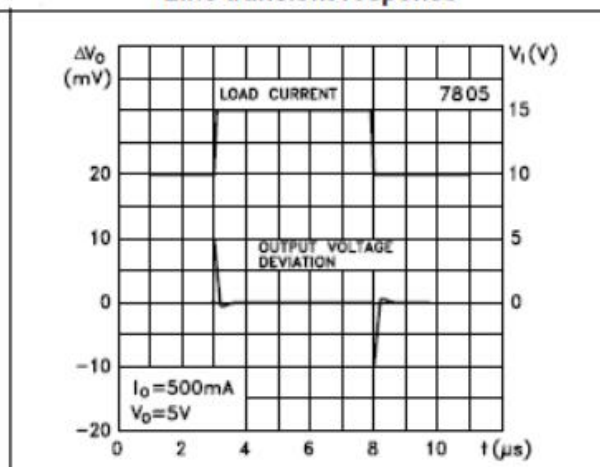
Quiescent current vs junction temp.



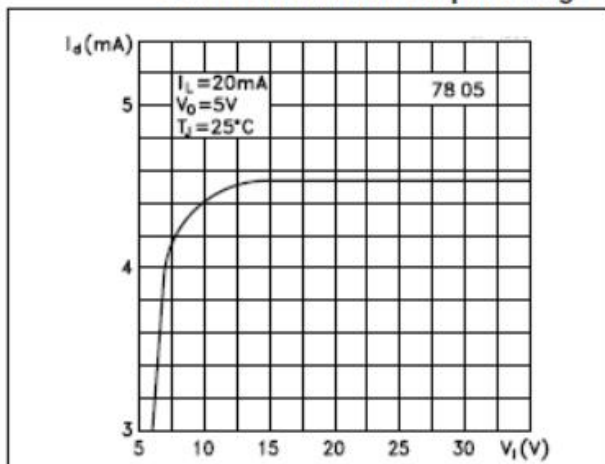
Load transient response



Line transient response



Quiescent current vs input voltage



Dropout voltage vs junction temp.

